

Data sheet acquired from Harris Semiconductor SCHS017

CMOS 18-Stage Static Shift Register

High-Voltage Types (20-Volt Rating)

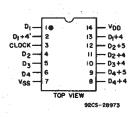
■ CD4006B types are composed of 4 separate shift register sections: two sections of four stages and two sections of five stages with an output tap at the fourth stage. Each section has an independent single-rail data path.

A common clock signal is used for all stages. Data are shifted to the next stage on negative-going transitions of the clock. Through appropriate connections of inputs and outputs, multiple register sections of 4, 5, 8, and 9 stages or single register sections of 10, 12, 13, 14, 16, 17 and 18 stages can be implemented using one CD4006B package. Longer shift register sections can be assembled by using more than one CD4006B.

To facilitate cascading stages when clock rise and fall times are slow, an optional output (D_1+4') that is delayed one-half clock-cycle, is provided (see Truth Table for Output from Term. 2).

The CD4006B types are supplied in 14-lead hermetic dual-in-line ceramic packages (D and F suffixes), 14-lead dual-in-line plastic packages (E suffix), and in chip form (H suffix).

TERMINAL ASSIGNMENT





ALL INPUTS (TERMINALS 1,3,4,5,6) PROTECTED BY CIMOS PROTECTION NETWORK

9205-28974

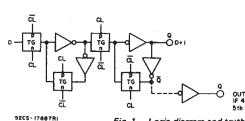
CD4006B Types

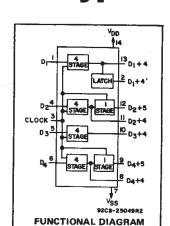
Features:

- Fully static operation
- Shifting rates up to 12 MHz @ 10 V (typ.)
- Permanent register storage with clock line high or low no information recirculation required
- 100% tested for quiescent current at 20 V
- Standardized, symmetrical output characteristics
- 5-V, 10-V, and 15-V parametric ratings
- Maximum input current of 1 μA at 18 V over full package-temperature range; 100 nA at 18 V and 25°C
- Noise margin (full package-temperature range) = 1 V at V_{DD} = 5 V 2 V at V_{DD} = 10 V 2.5 V at V_{DD} = 15 V
- Meets all requirements of JEDEC Tentative
 Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

Applications:

- Serial shift registers F requency division
- Time delay circuits





TRUTH TABLE FOR SHIFT REGISTER STAGE

D	CL♣	D + 1
0	7	0
1	7	1
х		NC

TRUTH TABLE FOR OUTPUT FROM TERM2

D ₁ +4	CL▲	D ₁ +4'
0		0
1		. 1
Х		NC
L^	<u> </u>	NC

1 = HIGH X = DON'T CARE
0 = LOW = LEVEL CHANGE
NC = NO CHANGE

Fig. 1 - Logic diagram and truth table (one register stage).

RECOMMENDED OPERATING CONDITIONS at $T_A = 25^{\circ}C$, Except as Noted. For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	V _{DD}	LIMITS		UNITS	
	(V)	Min.	Max.	1	
Supply-Voltage Range (For T _A = Full Package Temperature Range)	_	3	18	V	
Clock Pulse Width, t _W	5 10 15	180 80 50		ns	
Data Setup Time, t _S	5 10 15	100 50 40	- - -	ns	
Data Hold Time, t _H	5 10 15	60 40 30	- - -	ns	
Clock Rise or Fall Time: t _r , t _f	5,10, 15	_	15	μS	
Clock Input Frequency, f _{CL}	5 10 15	_ _ _	2.5 5 7	MHz	

CD4006B Types

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (V _{DD})	
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	0.5V to V _{DD} +0.5V
DC INPUT CURRENT, ANY ONE INPUT	
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	500mW
For T _A = +100°C to +125°C	Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package	Types)
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)	
LEAD TEMPERATURE (DURING SOLDERING):	
At distance 1/16 \pm 1/32 inch (1.59 \pm 0.79mm) from case for 10s m	ax+265°C

STATIC ELECTRICAL CHARACTERISTICS

CHARACTER-	CONE	OITIO	vs	LIMITS AT INDICATED TEMPERATURES (°C)						UNITS	
ISTIC	Vo	VIN	VDD						+25		UNITS
	(v)	(V)	(V)	-55	40	+85	+125	Min.	Тур.	Max.	
Quiescent Device	_	0,5	5	5	5	150	150	-	0.04	5	
Current,	_	0,10	10	10	10	300	300	-	0.04	10	μА
IDD Max.	-	0,15	15	20	20	600	600	-	0.04	20	μΑ
		0,20	20	100	100	3000	3000	-	0.08	100	
Output Low	0.4	0,5	5	0.64	0.61	0.42	0.36	0.51	1	-	
(Sink) Current	0.5	0,10	10	1.6	1.5	1.1	0.9	1.3	2.6		
IOL Min.	1.5	0,15	15	4.2	4	2.8	2.4	34	6.8	-	:
Output High	4.6	0,5	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	-	mA
(Source) Current, IOH Min.	2.5	0,5	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	-	
	9.5	0,10	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	-	-
тон ******	13.5	0,15	15	-4.2	-4	-2.8	2.4	-3.4	-6.8	-	
Output Voltage:	_	0,5	5		0	.05		-	0	0.05	
Low-Level, VOL Max.	_	0,10	10	0.05				-	0	0.05	
VOL Wax.		0,15	15		0	.05		_	0	0.05	v
Output Voltage:		0,5	5		4	.95		4.95	5	-	\ \ \ \
High-Level,	_	0,10	10		9	.95		9.95	10	-	
VOH Min.		0,15	15		14	.95		14.95	15	-	
Input Low	0.5, 4.5	_	5		1	.5		_		1.5	
Voltage,	1, 9	_	10			3			_	3	
VIL Max.	1.5,13.5	-	15	4				. —	_	4	.,
Input High	0.5, 4.5	_	5	3.5			3.5	_	_	٧	
Voltage,	1, 9	_	10		7				-		
VIH Min.	1.5,13.5	-	15		11			11	_	_	
Input Current IIN Max.	-	0,18	18	±0.1	±0.1	±1	±1	_	±10-5	±0.1	μА

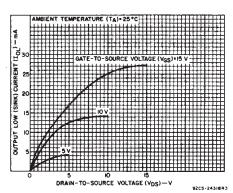


Fig. 2 – Typical output low (sink) current characteristics.

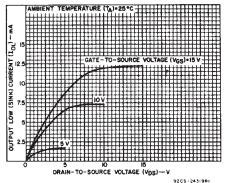


Fig. 3 — Minimum output low (sink) current characteristics.

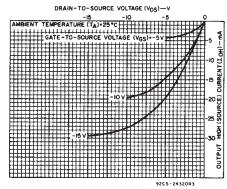


Fig. 4 — Typical output high (source) current characteristics.

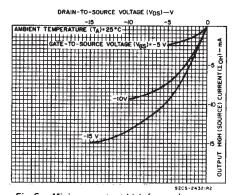


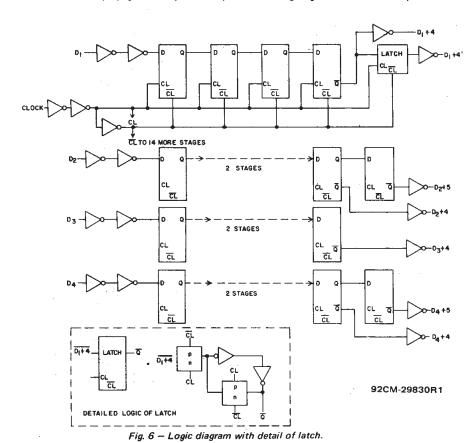
Fig. 5 — Minimum output high (source) current characteristics.

CD4006B Types

DYNAMIC ELECTRICAL CHARACTERISTICS at $T_{\rm A}$ = 25°C; Input $t_{\rm t}$, $t_{\rm t}$ = 20 ns, $C_{\rm L}$ = 50 pF, $R_{\rm L}$ = 200 k Ω

CHARACTERISTIC	TEST CONDITIONS		UNITS		
CHARACTERISTIC	V _{DD} (V)	MIN. TYP.		MAX.	ONIIS
Propagation Delay Time,	5	_	200	400	
tent, teth	10	_	100	200	ns
	- 15	_	80	160	
Transition Time,	5		100	200	
t _{THL} , t _{TLH}	10	_	50	100	ns
	15	_	40	80	:
Minimum Data Setup Time,	5	-	50	100	
ts	10	_	25	50	ns
	15	_	20	40	
Minimum Clock Pulse Width,	5		100	200	
t _w .	10	_	45	90	ns
	15	_	30	60	
Maximum Clock Input	5	2.5	5	_	
Frequency, fcL	10	5	10	_	MHz
	15	7	14	-	
Maximum Clock Input Rise or	5			15	
Fall Time, trCL, trCL*	10	–	[-	15	μs
	15	–	_	15	
Input Capacitance, Cin	Any Input		5	7.5	ρF

^{*}If more than one unit is cascaded t_iCL should be made less than or equal to the sum of the transition time and the fixed propagation delay of the output of the driving stage for the estimated capacitive load.



AMBIENT TEMPERATURE (TA)-25°C

Fig. 7 – Typical transition time as a function of load capacitance.

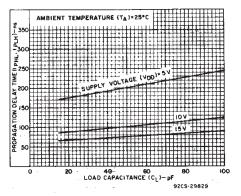


Fig. 8 — Typical propagation delay time as a function of load capacitance.

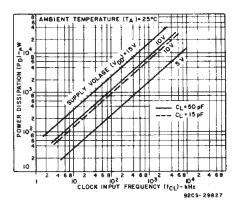


Fig. 9 — Typical dyanamic power dissipation as a function of clock frequency.

CD4006B Types

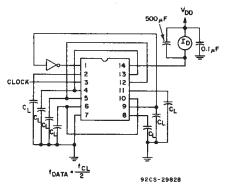


Fig. 10 - Dynamic power dissipation test circuit.

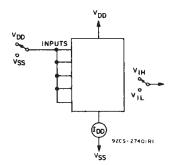


Fig. 11 - Quiescent device current test circuit.

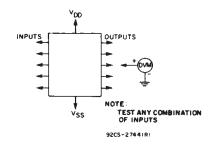


Fig. 12 - Input voltage test circuit.

3

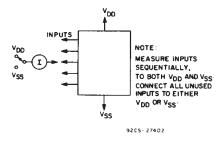
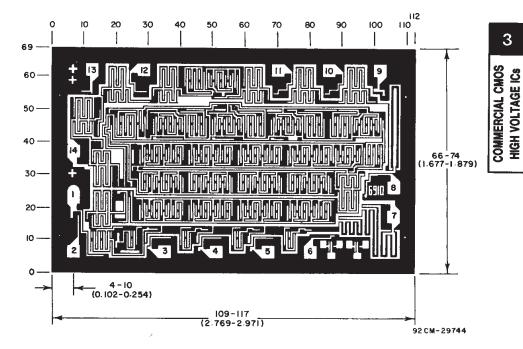


Fig. 13 - Input current test circuit.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10⁻³ inch).

Dimensions and pad layout for CD4006BH.



PACKAGE OPTION ADDENDUM

28-Feb-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins Package Qty	Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4006BE	OBSOLETE	PDIP	N	14	None	Call TI	Call TI
CD4006BF3A	ACTIVE	CDIP	J	14 1	None	Call TI	Level-NC-NC-NC

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - May not be currently available - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

None: Not yet available Lead (Pb-Free).

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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Green (RoHS & no Sb/Br): TI defines "Green" to mean "Pb-Free" and in addition, uses package materials that do not contain halogens, including bromine (Br) or antimony (Sb) above 0.1% of total product weight.

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDECindustry standard classifications, and peak solder temperature.

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